

L Number	Hits	Search Text	DB	Time stamp
1	2824394	memory or storage	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 11:15
2	199	(memory or storage) and (cell or element or unit) with phase near3 change with amorphous	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 11:17
3	101	(memory or storage) and (cell or element or unit) with phase near3 change with amorphous with state	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 12:03
4	50	(memory or storage) and phase near3 change with state with threshold	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 12:05
5	24	((memory or storage) and phase near3 change with state with threshold) and chalcogen\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 12:05

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3	101	(memory or storage) and (cell or element or unit) with phase near3 change with amorphous with state	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 12:03
4	50	(memory or storage) and phase near3 change with state with threshold	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 12:05
5	24	((memory or storage) and phase near3 change with state with threshold) and chalcogen\$5	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 12:34
6	0	(memory or storage) and program\$5 with phase near3 change with second with threshold with state	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 12:37
7	12	(memory or storage) and program\$5 with phase near3 change with threshold with state	USPAT; US-PGPUB; EPO; JPO; DERWENT	2004/06/13 12:38